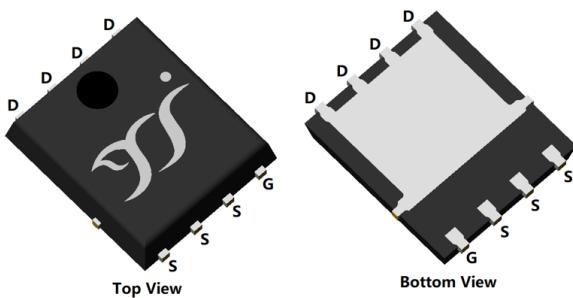
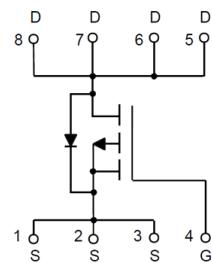




P-Channel Enhancement Mode Field Effect Transistor



PDFN5060-8L



Product Summary

- V_{DS} -100V
- I_D -25A
- $R_{DS(ON)}$ (at $V_{GS}=-10V$) <56 mohm
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) <62 mohm
- 100% EAS Tested
- 100% ∇V_{DS} Tested

General Description

- Split gate trench MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- DC-DC Converters
- Power management functions

■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	-100	V
Gate-source Voltage		V_{GS}	± 20	V
Drain Current	Ta=25°C	I_D	-5	A
	Ta=100°C		-3	
	Tc=25°C		-25	
	Tc=100°C		-16	
Pulsed Drain Current ^A		I_{DM}	-100	A
Avalanche energy ^B		EAS	162	mJ
Total Power Dissipation	Ta=25°C	P_D	2.5	W
	Ta=100°C		1	
	Tc=25°C		88	
	Tc=100°C		35.2	
Junction and Storage Temperature Range		T_J, T_{STG}	-55~+150	°C

■ Thermal resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient ^D	$t \leq 10S$	R_{BJA}	15	20	°C/W
Thermal Resistance Junction-to-Ambient ^D	Steady-State		40	50	
Thermal Resistance Junction-to-Case	Steady-State		1.15	1.42	

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJG25GP10A	F1	YJG25GP10A	5000	10000	100000	13" reel



YJG25GP10A

■ Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions		Min	Typ	Max	Units
Static Parameter							
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$		-100			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=-100\text{V}, V_{\text{GS}}=0\text{V}$	$T_J=25^\circ\text{C}$			-1	μA
			$T_J=55^\circ\text{C}$			-5	
Gate-Body Leakage Current	I_{GSS}	$V_{\text{GS}}= \pm 20\text{V}, V_{\text{DS}}=0\text{V}$				± 100	nA
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$		-1.0	-1.8	-2.5	V
Static Drain-Source On-Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}= -10\text{V}, I_{\text{D}}=-15\text{A}$			42	56	$\text{m}\Omega$
		$V_{\text{GS}}= -4.5\text{V}, I_{\text{D}}=-7\text{A}$			46	62	
Diode Forward Voltage	V_{SD}	$I_{\text{S}}=-15\text{A}, V_{\text{GS}}=0\text{V}$				-1.3	V
Maximum Body-Diode Continuous Current	I_{S}					-25	A
Dynamic Parameters							
Input Capacitance	C_{iss}	$V_{\text{DS}}=-50\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$			2100		pF
Output Capacitance	C_{oss}				236		
Reverse Transfer Capacitance	C_{rss}				48		
Switching Parameters							
Total Gate Charge	$Q_g(-10\text{V})$	$V_{\text{GS}}=-10\text{V}, V_{\text{DS}}=-50\text{V}, I_{\text{D}}=-5\text{A}$			40		nC
Total Gate Charge	$Q_g(-4.5\text{V})$				19.4		
Gate-Source Charge	Q_{gs}				7.8		
Gate-Drain Charge	Q_{gd}				8.6		
Reverse Recovery Charge	Q_{rr}	$I_{\text{f}}=-5\text{A}, di/dt=100\text{A/us}$			280		ns
Reverse Recovery Time	t_{rr}				104		
Turn-on Delay Time	$t_{\text{D(on)}}$				13		
Turn-on Rise Time	t_{r}				39		
Turn-off Delay Time	$t_{\text{D(off)}}$	$V_{\text{GS}}=-10\text{V}, V_{\text{DD}}=-50\text{V}, I_{\text{DS}}=-5\text{A}$ $R_{\text{GEN}}=6\Omega$			100.1		ns
Turn-off fall Time	t_{f}				105.3		

- A. Repetitive rating; pulse width limited by max. junction temperature.
- B. $V_{\text{DD}}=50\text{V}$, $R_{\text{G}}=25\Omega$, $L=0.5\text{mH}$.
- C. P_d is based on max. junction temperature, using junction-case thermal resistance.
- D. The value of $R_{\theta JA}$ is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with $TA = 25^\circ\text{C}$. The Power dissipation PDSM is based on $R_{\theta JA} \leq 10\text{s}$ and the maximum allowed junction temperature of 150°C . The value in any given application depends on the user's specific board design

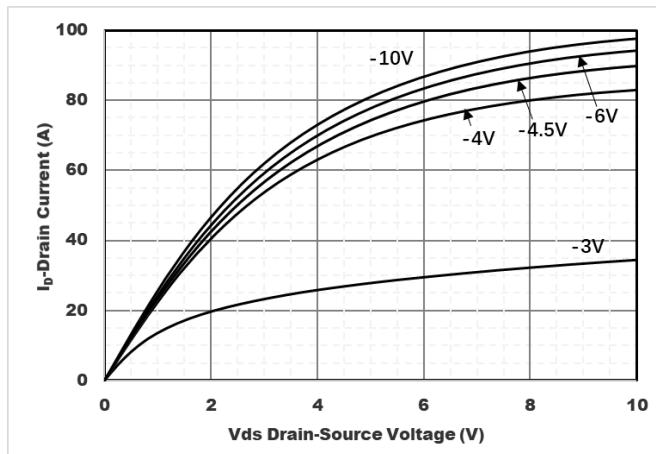
**■ Typical Performance Characteristics**

Figure1. Output Characteristics

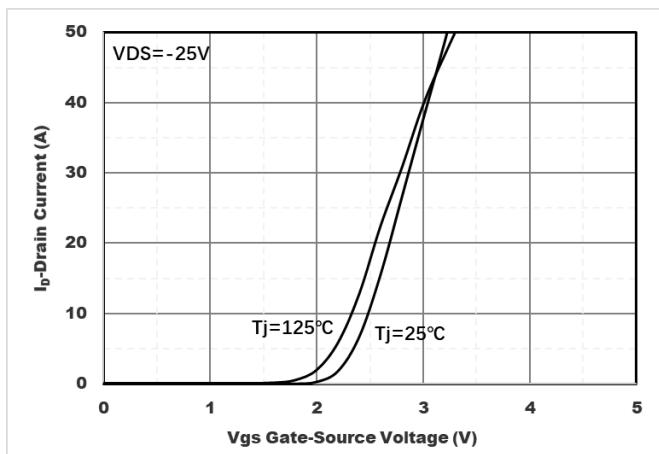


Figure2. Transfer Characteristics

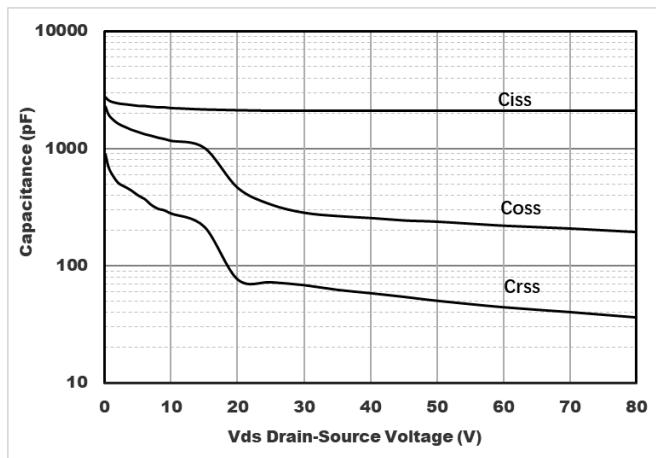


Figure3. Capacitance Characteristics

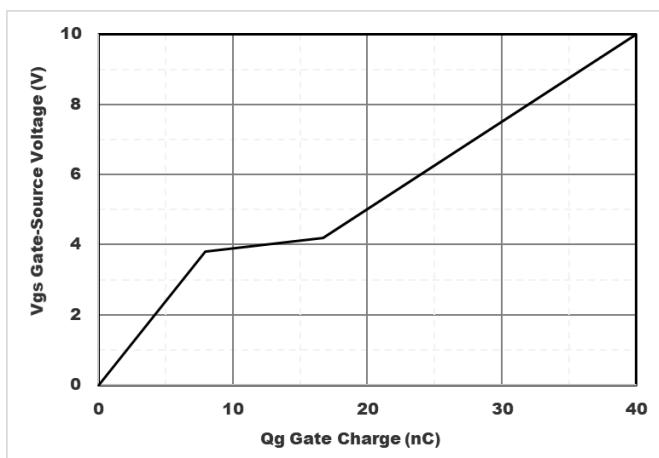


Figure4. Gate Charge

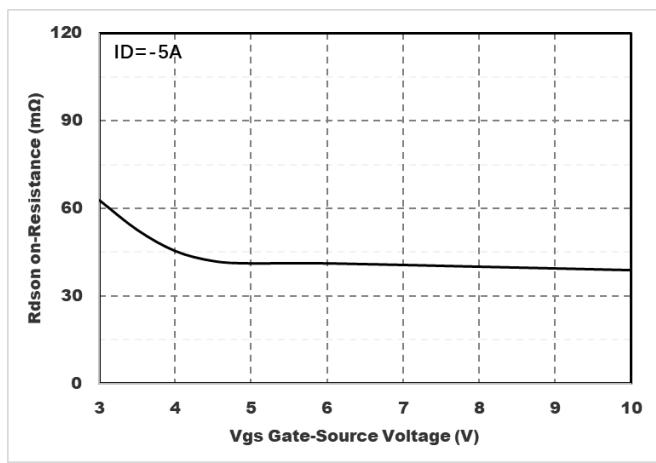


Figure5. : On-Resistance vs. Gate to Source Voltage

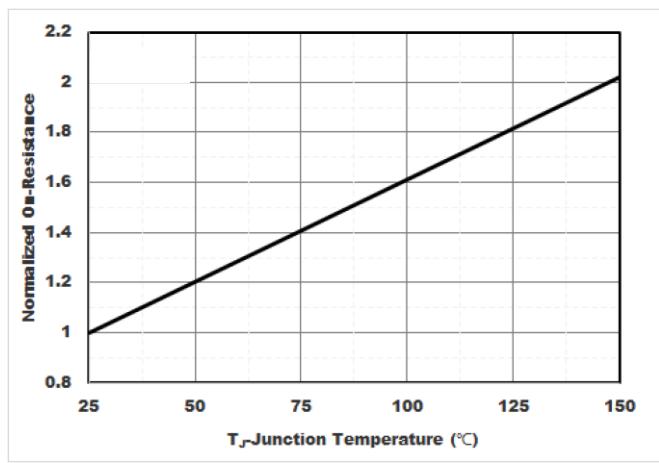


Figure6. Normalized On-Resistance

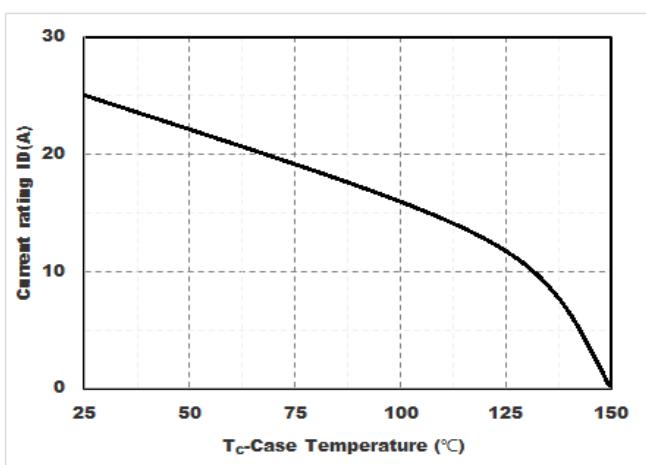


Figure7. Drain current

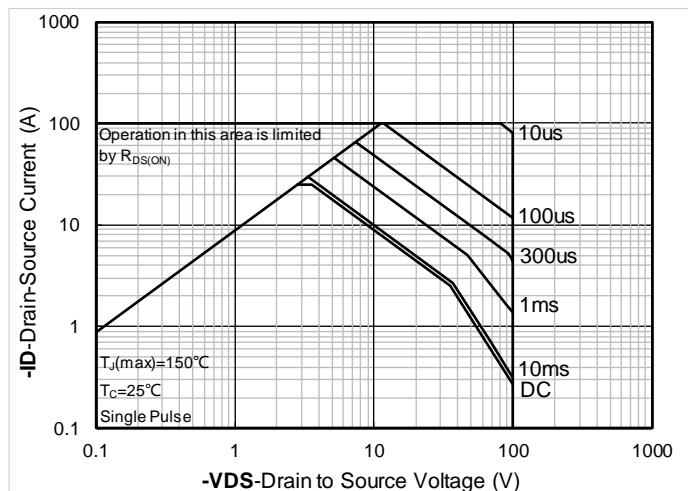


Figure8.Safe Operation Area

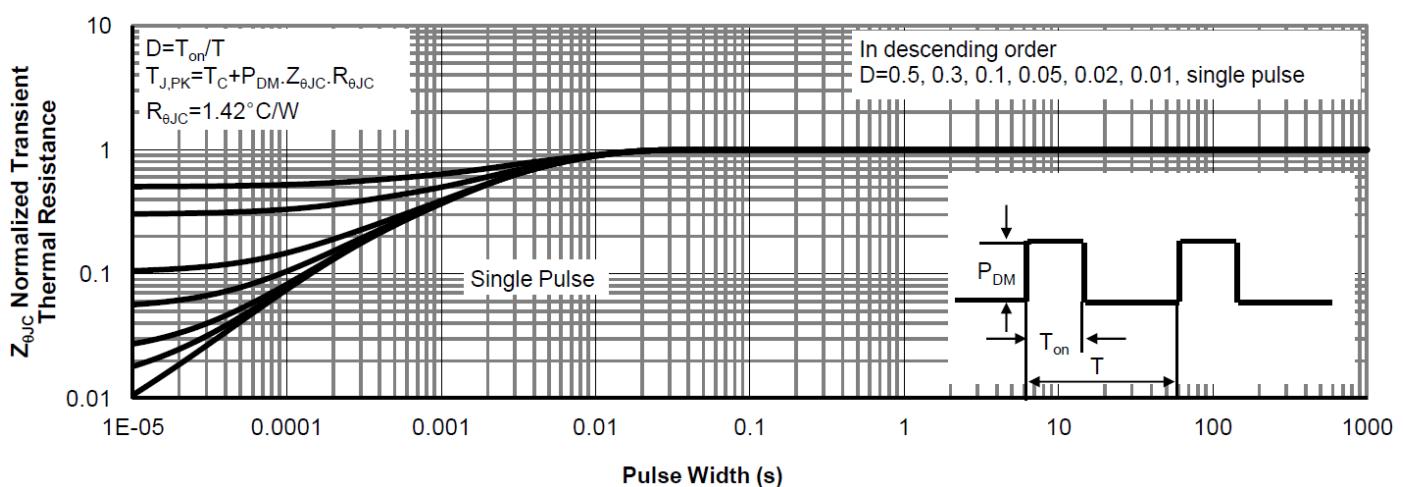
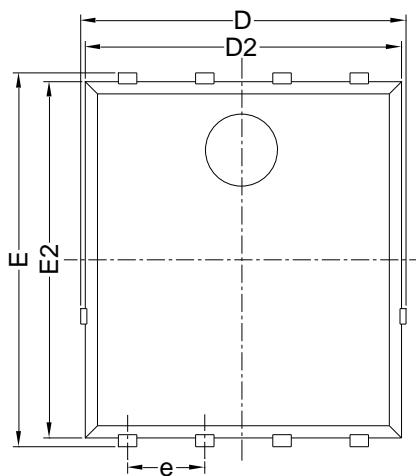


Figure9.Normalized Maximum Transient thermal impedance

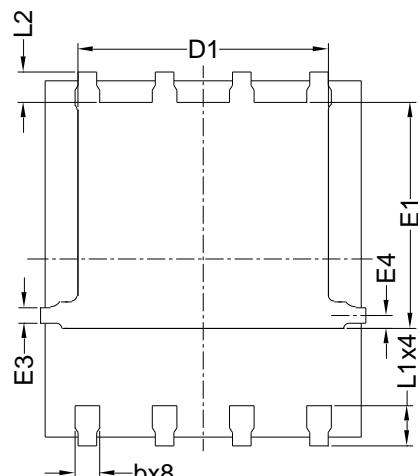


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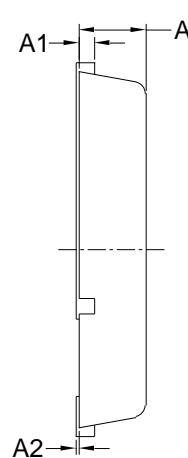
■ PDFN5060-8L-B-1.1MM Package information



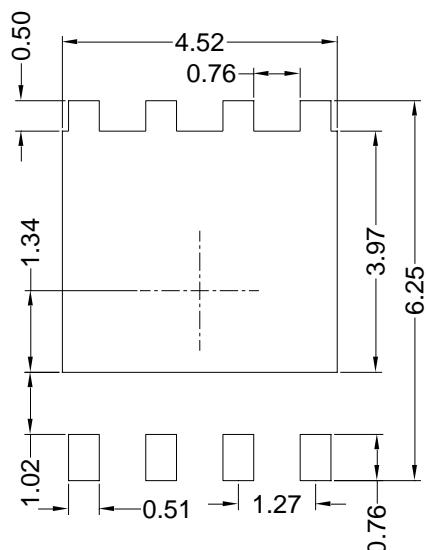
Top View
正面视图



Bottom View
背面视图



Side View
侧面视图



Suggested Solder Pad Layout
Top View

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	5.15	5.35	5.55
E	5.95	6.15	6.35
A	1.00	1.10	1.20
A1	0.254 BSC		
A2			0.10
D1	3.92	4.12	4.32
E1	3.52	3.72	3.92
D2	5.00	5.20	5.40
E2	5.66	5.86	6.06
E3	0.254 REF		
E4	0.21 REF		
L1	0.56	0.66	0.76
L2	0.50 BSC		
b	0.31	0.41	0.51
e	1.27 BSC		

Note:

1. Controlling dimension:in millimeters.
2. General tolerance: $\pm 0.10\text{mm}$.
3. The pad layout is for reference purposes only.



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